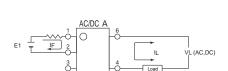


Parameter	Symbol	Rating	Units	
Load Voltage	VL	1800	V	
Load Current	lL .	0.450	Α	
Leakage Current	Leak	0.1	uA	
Low Out Capacitance	Cout	135	pF	





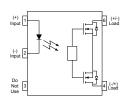












- 1. LED Anode
- 2. LED Cathode
- 4. Drain (MOS FET)
- 6. Drain (MOS FET)

APSEMI PhotoRelays

APSEMI Photorelays are the most reliable, technically advanced logic-to-power interface devices. Their basic function is to take a low current signal from a microprocessor to control the switching of both AC and DC loads, while providing an isolation barrier between logic and power.

While this function is common to all relays, Photorelays provide distinct advantages over their mechanical counterparts including:

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- · Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI

- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load
- switching
- Small package size

Applications

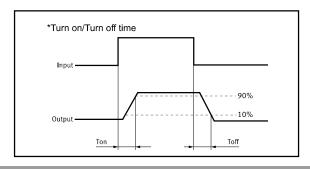
These advantages make APSEI Photorelays the ideal choice for:

- Telecom/Datacom switching
- Multiplexers
- Meter reading systems
- Data acquisition
- Medical equipment
- Battery monitoring
- I/O Sub-Systems

- Robotics
- Aerospace
- Home/Safety security systems
- Process Control
- Energy Management
- Reed Relay EMR Replacement
- Programmable Controllers

TPYES

Cotogon	Out	Output Rating		Part No.	Packing Quantity	
Category Load Voltage Load Current		Load Current	Package	Part No.		
AC/DC 1800V 450mA		DIP-5	APV278G1E	50pcs /tube		
AC/DC 1800V	18007	450mA	SMD-5	APV278G1EH	1000pcs /reel	





Absolute Maximum Ratings (Ta = 25°C)

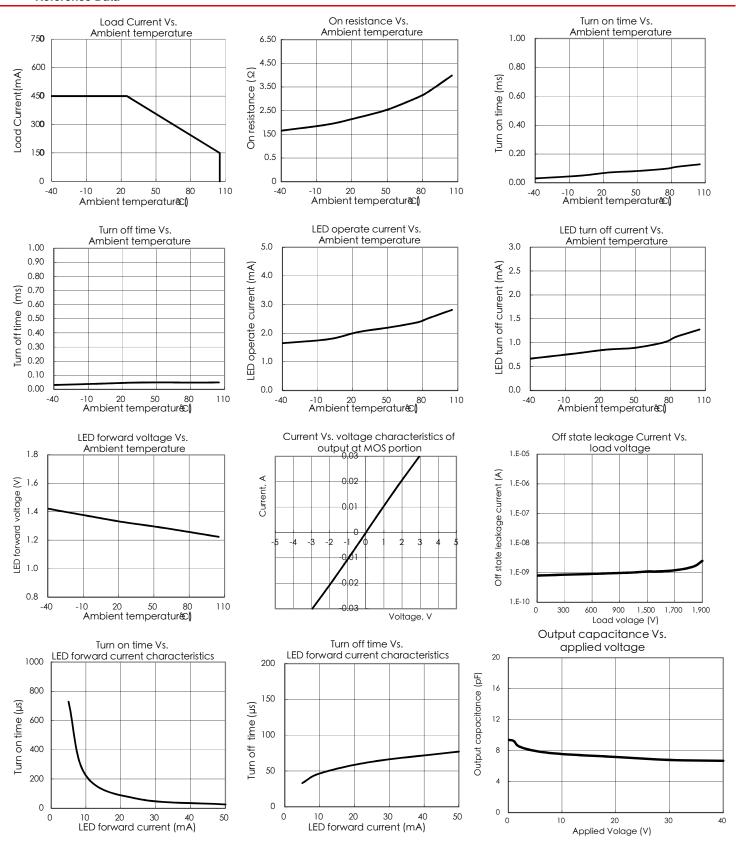
	Item	Symbol	Value	Units	Note
	Continuous LED Current	lF	50	mA	
Input	Peak LED Current	Ігр	500	mA	f=100Hz, duty=1%
·	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	Pın	75	mW	
Output	Load Voltage	V∟	1800	V(AC peak or DC)	
	Load Current	l.	450	mA	
	Peak Load Current	Peak	1000	mA	100ms(1 pulse)
	Output Power Dissipation	Pout	450	mW	
Total Power	Dissipation	Р⊤	500	mW	
I/O Breakdov	vn Vo l tage	V _{I/O}	5000	Vrms	RH=60%, 1min
Operating Te	emperature	Торг	-40 to 85	°C	
Storage Temperature		T _{stg}	-40 to 100	°C	
Pin Soldering	g Temperature	T _{sol}	260	℃	10 sec max.

Electrical Characteristics (Ta = 25°C)

	Item	Symbol	MIN.	TYP.	MAX.	Units	Conditions	
	LED Forward Voltage	VF		1.33	1.5	٧	I⊧=10mA	
	Operation LED Current	Fon		2.0	5.0	mA		
Input	Recovery LED Current	Foff		0.35	0.8	mA		
	Recovery LED Voltage	V _{Foff}	0.7	1.20		٧		
							IF=10mA,IL= Rating,	
Output	On-Resistance	Ron		1.80	3.00	Ω	Time to flow is within 1 sec.	
	Off-State Leakage Current	Leak			0.01	uA	V₋=Rating	
	Output Capacitance	Cout		135		pF	V∟=0, f=1MHz	
Transmis	Turn-On Time	Ton		0.75	3.0	ms	IF=10mA, I L=Rating	
sion	Turn-Off Time	Toff		0.05	0.1	ms		
Cauplad	I/O Isolation Resistance	R _{I/O}	10 ¹⁰			Ω	DC500V	
Coupled	I/O Capacitance	C _{I/O}		0.8	1.3	pF	f=1MHz	



Reference Data





Dimensions and DIP-5 Package

Unit: mm

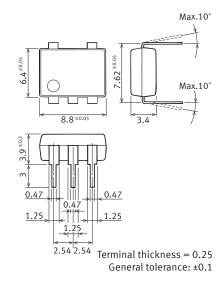
Marking



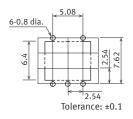
Lable



Through hole terminal type



PC board pattern (Bottom view)



DIP Tape dimensions Unit: mm

Devices are packaged in a tube so that pin No. 1 is on the stopper B side. Observe correct orientation when mounting them on PC boards.

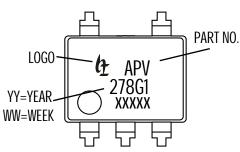




Dimensions and SMD-5 Package

Unit: mm

Marking

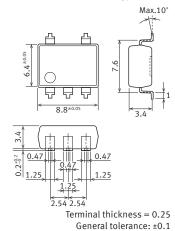


Lable



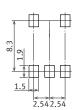
Tape dimensions (tape reel)

Surface mount terminal type

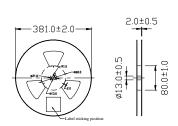


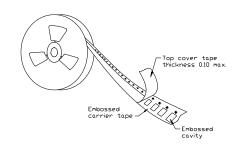
Recommended mounting pad

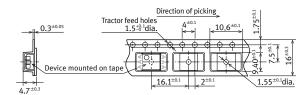
(Top view)



Tolerance: ±0.1



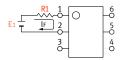


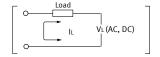




Using Methods

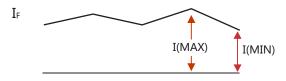
Examples of resistance value to control LED forward current (IF=5mA)





E1	R1 (Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9KΩ
24V	4.1K Ω

LED forward current must be more than 5mA, at I(MIN), and less than 30mA, at I(MAX).



Recommended Operating Conditions

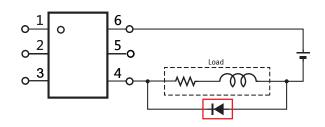
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

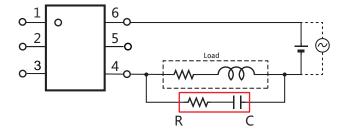
Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	lF	5.0	7.0	30	mA

Protection Circuit

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.

CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.





When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.



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